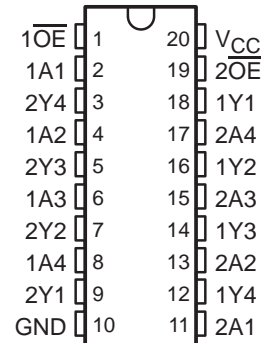


# SN74LVCZ240A OCTAL BUFFER/DRIVER WITH 3-STATE OUTPUTS

SCES273B – JUNE 1999 – REVISED JANUARY 2000

- **EPIC™ (Enhanced-Performance Implanted CMOS) Submicron Process**
- **Typical  $V_{OLP}$  (Output Ground Bounce)**  
<0.8 V at  $V_{CC} = 3.3$  V,  $T_A = 25^\circ\text{C}$
- **Typical  $V_{OHV}$  (Output  $V_{OH}$  Undershoot)**  
>2 V at  $V_{CC} = 3.3$  V,  $T_A = 25^\circ\text{C}$
- **$I_{off}$  and Power-Up 3-State Support Hot Insertion**
- **Supports Mixed-Mode Signal Operation on All Ports (5-V Input/Output Voltage With 3.3-V  $V_{CC}$ )**
- **Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II**
- **Package Options Include Shrink Small-Outline (DB), Plastic Thin Very Small-Outline (DGV), Small-Outline (DW), and Thin Shrink Small-Outline (PW) Packages**

DB, DGV, DW, OR PW PACKAGE  
(TOP VIEW)



## description

This octal buffer/driver is designed for 2.7-V to 3.6-V  $V_{CC}$  operation.

The SN74LVCZ240A is designed specifically to improve the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

This device is organized as two 4-bit buffers/drivers with separate output-enable ( $\overline{OE}$ ) inputs. When  $\overline{OE}$  is low, the device passes data from the A inputs to the Y outputs. When  $\overline{OE}$  is high, the outputs are in the high-impedance state.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of these devices as translators in a mixed 3.3-V/5-V system environment.

When  $V_{CC}$  is between 0 and 1.5 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for hot-insertion applications using  $I_{off}$  and power-up 3-state. The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

The SN74LVCZ240A is characterized for operation from  $-40^\circ\text{C}$  to  $85^\circ\text{C}$ .



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 **TEXAS  
INSTRUMENTS**

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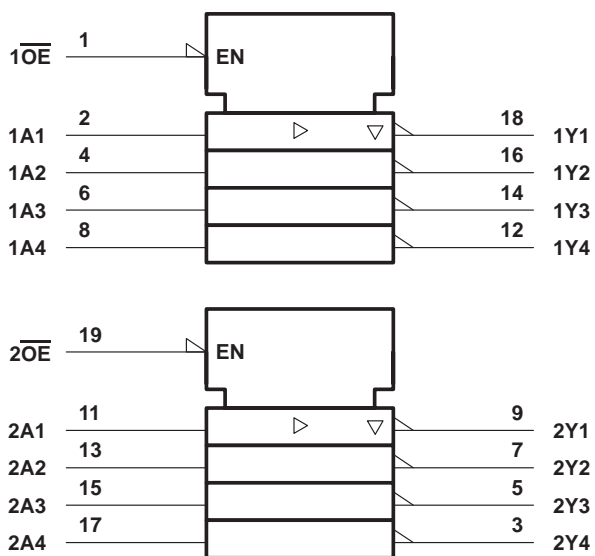
# SN74LVCZ240A OCTAL BUFFER/DRIVER WITH 3-STATE OUTPUTS

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FUNCTION TABLE  
(each buffer)

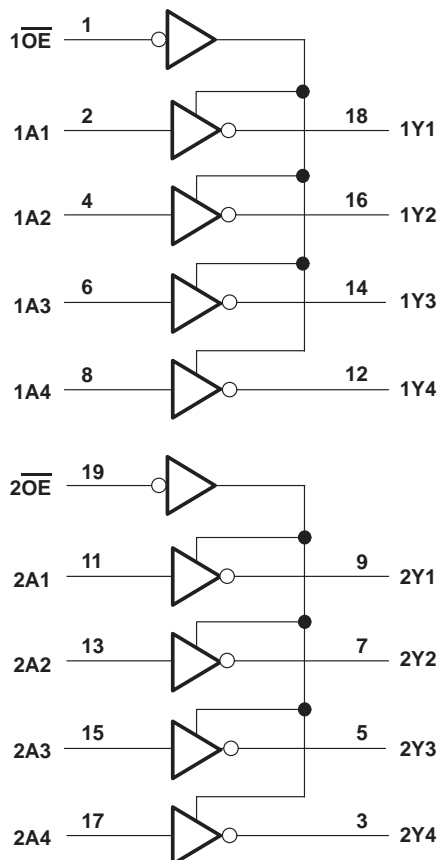
INPUTS		OUTPUT
$\overline{OE}$	A	Y
L	H	L
L	L	H
H	X	Z

## logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

## logic diagram (positive logic)



# SN74LVCZ240A OCTAL BUFFER/DRIVER WITH 3-STATE OUTPUTS

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## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, $V_{CC}$ .....	–0.5 V to 6.5 V
Input voltage range, $V_I$ (see Note 1) .....	–0.5 V to 6.5 V
Voltage range applied to any output in the high-impedance or power-off state, $V_O$ (see Note 1) .....	–0.5 V to 6.5 V
Voltage range applied to any output in the high or low state, $V_O$ (see Notes 1 and 2) .....	–0.5 V to $V_{CC} + 0.5$ V
Input clamp current, $I_{IK}$ ( $V_I < 0$ ) .....	–50 mA
Output clamp current, $I_{OK}$ ( $V_O < 0$ ) .....	–50 mA
Continuous output current, $I_O$ .....	±50 mA
Continuous current through $V_{CC}$ or GND .....	±100 mA
Package thermal impedance, $\theta_{JA}$ (see Note 3): DB package .....	115°C/W
DGV package .....	146°C/W
DW package .....	97°C/W
PW package .....	128°C/W
Storage temperature range, $T_{stg}$ .....	–65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.  
 2. The value of  $V_{CC}$  is provided in the recommended operating conditions table.  
 3. The package thermal impedance is calculated in accordance with JESD 51.

## recommended operating conditions (see Note 4)

		MIN	MAX	UNIT
$V_{CC}$	Supply voltage	2.7	3.6	V
$V_{IH}$	High-level input voltage	$V_{CC} = 2.7$ V to 3.6 V		V
$V_{IL}$	Low-level input voltage	$V_{CC} = 2.7$ V to 3.6 V		V
$V_I$	Input voltage	0	5.5	V
$V_O$	Output voltage	High or low state	0	$V_{CC}$
		3-state	0	5.5
$I_{OH}$	High-level output current	$V_{CC} = 2.7$ V	–12	mA
		$V_{CC} = 3$ V	–24	
$I_{OL}$	Low-level output current	$V_{CC} = 2.7$ V	12	mA
		$V_{CC} = 3$ V	24	
$\Delta t/\Delta v$	Input transition rise or fall rate		6	ns/V
$\Delta t/\Delta V_{CC}$	Power-up ramp rate		150	µs/V
$T_A$	Operating free-air temperature	–40	85	°C

NOTE 4: All unused inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



**SN74LVC240A**  
**OCTAL BUFFER/DRIVER**  
**WITH 3-STATE OUTPUTS**

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**electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP†	MAX	UNIT
V <sub>OH</sub>	I <sub>OH</sub> = -100 μA	2.7 V to 3.6 V	V <sub>CC</sub> -0.2			V
	I <sub>OH</sub> = -12 mA	2.7 V	2.2			
		3 V	2.4			
	I <sub>OH</sub> = -24 mA	3 V	2.2			
V <sub>OL</sub>	I <sub>OL</sub> = 100 μA	2.7 V to 3.6 V			0.2	V
	I <sub>OL</sub> = 12 mA	2.7 V			0.4	
	I <sub>OL</sub> = 24 mA	3 V			0.55	
I <sub>I</sub>	V <sub>I</sub> = 0 to 5.5 V	3.6 V			±5	μA
I <sub>off</sub>	V <sub>I</sub> or V <sub>O</sub> = 5.5 V	0			±5	μA
I <sub>OZ</sub>	V <sub>O</sub> = 0 to 5.5 V	3.6 V			±5	μA
I <sub>OZPU</sub>	V <sub>O</sub> = 0.5 to 2.5 V, $\overline{OE}$ = don't care	0 to 1.5 V			±5	μA
I <sub>OZPD</sub>	V <sub>O</sub> = 0.5 to 2.5 V, $\overline{OE}$ = don't care	1.5 V to 0			±5	μA
I <sub>CC</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	3.6 V	I <sub>O</sub> = 0		100	μA
	3.6 V ≤ V <sub>I</sub> ≤ 5.5 V‡				100	
ΔI <sub>CC</sub>	One input at V <sub>CC</sub> - 0.6 V, Other inputs at V <sub>CC</sub> or GND	2.7 V to 3.6 V			100	μA
C <sub>i</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	3.3 V		3.5		pF
C <sub>o</sub>	V <sub>O</sub> = V <sub>CC</sub> or GND	3.3 V		5.5		pF

† All typical values are at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C.

‡ This applies in the disabled state only.

**switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 2.7 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		UNIT
			MIN	MAX	MIN	MAX	
t <sub>pd</sub>	A or B	B or A		7.5	1.3	6.5	ns
t <sub>en</sub>	$\overline{OE}$	A or B		9	1.1	8	ns
t <sub>dis</sub>	$\overline{OE}$	A or B		8	1.4	7	ns

**operating characteristics, T<sub>A</sub> = 25°C**

PARAMETER	TEST CONDITIONS	V <sub>CC</sub> = 3.3 V		UNIT
		TYP		
C <sub>pd</sub> Power dissipation capacitance per buffer/driver	Outputs enabled	f = 10 MHz	37	pF
	Outputs disabled		3	

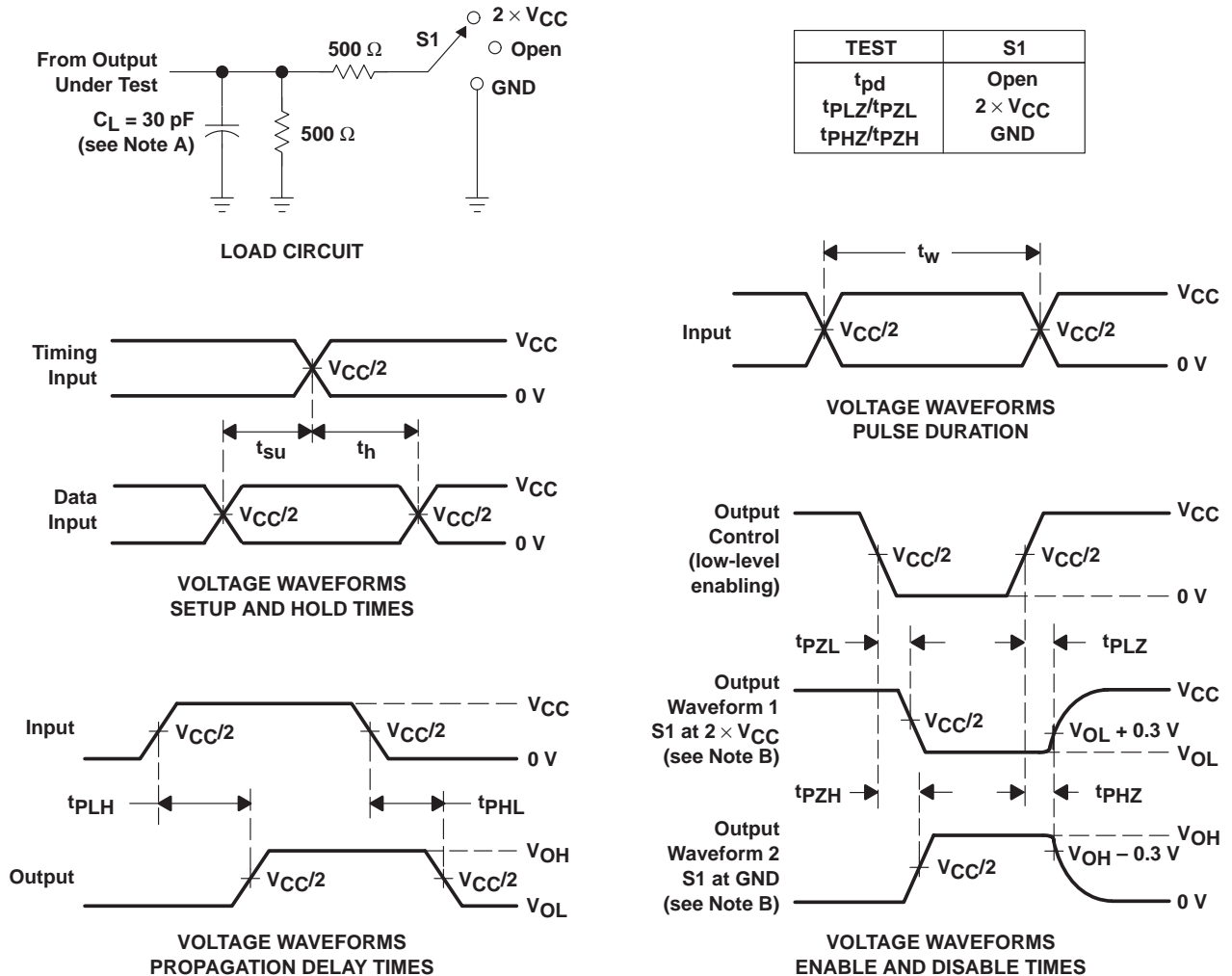


# SN74LVC2240A OCTAL BUFFER/DRIVER WITH 3-STATE OUTPUTS

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## PARAMETER MEASUREMENT INFORMATION

$V_{CC} = 2.7\text{ V AND } 3.3\text{ V} \pm 0.3\text{ V}$



- NOTES:
- $C_L$  includes probe and jig capacitance.
  - Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10\text{ MHz}$ ,  $Z_O = 50\ \Omega$ ,  $t_r \leq 2\text{ ns}$ ,  $t_f \leq 2\text{ ns}$ .
  - The outputs are measured one at a time with one transition per measurement.
  - $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

Figure 1. Load Circuit and Voltage Waveforms

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